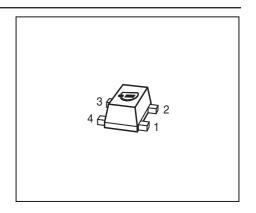


### Low Noise Silicon Bipolar RF Transistor

- For low current applications
- Minimum noise figure NF<sub>min</sub> = 1.25 dB at 1.8 GHz
  Outstanding G<sub>ms</sub> = 22.5 dB at 1.8 GHz
- Transition frequency  $f_T$  = 25 GHz
- Pb-free (RoHS compliant) and halogen-free thin small flat package (1.4 x 0.8 x 0.59 mm) with visible leads
- Qualification report according to AEC-Q101 available







### **ESD** (Electrostatic discharge) sensitive device, observe handling precaution!

Туре	Marking	Pin Configuration					Package	
BFP405F	ALs	1=B	2=E	3=C	4=E	-	-	TSFP-4

# **Maximum Ratings** at $T_A$ = 25 °C, unless otherwise specified

Parameter	Symbol	Value	Unit
Collector-emitter voltage	V <sub>CEO</sub>		V
T <sub>A</sub> = 25 °C		4.5	
T <sub>A</sub> = -55 °C		4.1	
Collector-emitter voltage	$V_{CES}$	15	
Collector-base voltage	$V_{\mathrm{CBO}}$	15	
Emitter-base voltage	V <sub>EBO</sub>	1.5	
Collector current	I <sub>C</sub>	25	mA
Base current	I <sub>B</sub>	3	
Total power dissipation <sup>1)</sup>	P <sub>tot</sub>	75	mW
<i>T</i> <sub>S</sub> ≤ 112 °C			
Junction temperature	$T_{J}$	150	°C
Storage temperature	T <sub>Stg</sub>	-55 150	

 $<sup>^{1}</sup>T_{\mathrm{S}}$  is measured on the emitter lead at the soldering point to the pcb

### **Thermal Resistance**

Parameter	Symbol	Value	Unit
Junction - soldering point <sup>1)</sup>	R <sub>thJS</sub>	500	K/W



**Electrical Characteristics** at  $T_A$  = 25 °C, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics	•			•	
Collector-emitter breakdown voltage	V <sub>(BR)CEO</sub>	4	5	_	V
$I_{\rm C}$ = 1 mA, $I_{\rm B}$ = 0	. ,				
Collector-emitter cutoff current	I <sub>CES</sub>	-	-	10	μΑ
$V_{CE} = 15 \text{ V}, V_{BE} = 0$					
Collector-base cutoff current	I <sub>CBO</sub>	-	-	100	nA
$V_{\rm CB} = 5 \text{ V}, I_{\rm E} = 0$					
Emitter-base cutoff current	I <sub>EBO</sub>	-	-	1	μΑ
$V_{\rm EB} = 0.5  \text{V}, I_{\rm C} = 0$					
DC current gain	h <sub>FE</sub>	60	95	130	_
$I_{\rm C}$ = 5 mA, $V_{\rm CE}$ = 4 V, pulse measured					

 $<sup>^{1}\</sup>mathrm{For}$  the definition of  $R_{\mathrm{thJS}}$  please refer to Application Note AN077 (Thermal Resistance Calculation)



**Electrical Characteristics** at  $T_A$  = 25 °C, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
AC Characteristics (verified by random sampling	g)				,
Transition frequency	f <sub>T</sub>	18	25	-	GHz
$I_{\rm C}$ = 10 mA, $V_{\rm CE}$ = 3 V, $f$ = 2 GHz					
Collector-base capacitance	C <sub>cb</sub>	-	0.05	0.1	pF
$V_{\text{CB}} = 2 \text{ V}, f = 1 \text{ MHz}, V_{\text{BE}} = 0$ ,					
emitter grounded					
Collector emitter capacitance	C <sub>ce</sub>	-	0.2	-	
$V_{CE} = 2 \text{ V}, f = 1 \text{ MHz}, V_{BE} = 0$ ,					
base grounded					
Emitter-base capacitance	C <sub>eb</sub>	-	0.25	-	
$V_{\text{EB}} = 0.5 \text{ V}, f = 1 \text{ MHz}, V_{\text{CB}} = 0$					
collector grounded					
Minimum noise figure	NF <sub>min</sub>	-	1.25	-	dB
$I_{C} = 2 \text{ mA}, V_{CE} = 2 \text{ V}, f = 1.8 \text{ GHz}, Z_{S} = Z_{Sopt}$					
Power gain, maximum stable <sup>1)</sup>	G <sub>ms</sub>	-	22.5	-	dB
$I_{\rm C}$ = 5 mA, $V_{\rm CE}$ = 2 V, $Z_{\rm S}$ = $Z_{\rm Sopt}$ ,					
$Z_{L} = Z_{Lopt}$ , $f = 1.8 \text{ GHz}$					
Insertion power gain	$ S_{21} ^2$	-	18	-	
$V_{CE} = 2 \text{ V}, I_{C} = 5 \text{ mA}, f = 1.8 \text{ GHz},$					
$Z_{\rm S} = Z_{\rm L} = 50 \ \Omega$					
Third order intercept point at output <sup>2)</sup>	IP3	-	14	-	dBm
$V_{CE} = 2 \text{ V}, I_{C} = 5 \text{ mA}, f = 1.8 \text{ GHz},$					
$Z_{\rm S} = Z_{\rm L} = 50 \ \Omega$					
1dB compression point at output	P <sub>-1dB</sub>	-	0	-	
$I_{\rm C}$ = 5 mA, $V_{\rm CE}$ = 2 V, $Z_{\rm S}$ = $Z_{\rm L}$ = 50 $\Omega$ ,					
f = 1.8 GHz					

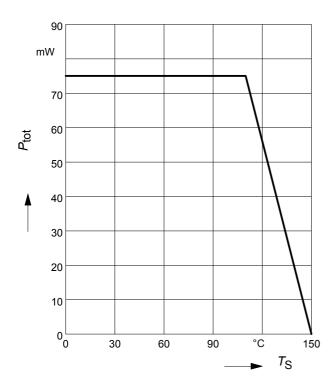
 $<sup>^{1}</sup>G_{\rm ms} = |S_{21} / S_{12}|$ 

<sup>&</sup>lt;sup>2</sup>IP3 value depends on termination of all intermodulation frequency components.

Termination used for this measurement is  $50\Omega$  from 0.1 MHz to 6 GHz



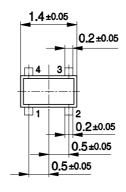
# Total power dissipation $P_{\text{tot}} = f(T_{\text{S}})$

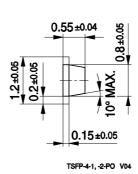




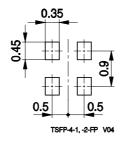
# Package Outline



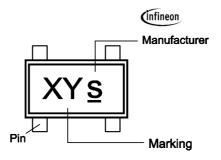




### **Foot Print**

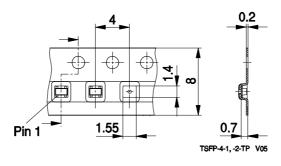


# Marking Layout (Example)



# Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel Reel ø330 mm = 10.000 Pieces/Reel





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